## 0.5-18 GHz High Power SPDT Reflective Switch

## Product Overview

Qorvo's TGS2353-2-SM is a single-pole, double-throw (SPDT) reflective switch packaged in a $4 \times 4 \mathrm{~mm}$ ceramic, air-cavity QFN.

Fabricated on Qorvo's QGaN25 0.25um GaN on SiC production process, the TGS2353-2-SM operates from 0.518 GHz and can switch up to 10 W with low insertion loss and high isolation.

The TGS2353-2-SM performance allows it to be used in a variety of applications across commercial and military markets; low and high power.

Lead-free and RoHS compliant

## Functional Block Diagram




QFN $4 \times 4$ mm 22L

## Key Features

- SPDT, Reflective
- Frequency Range: 0.5 to 18 GHz
- Input Power: up to 10 W
- Insertion Loss: <1.5 dB
- Isolation: 30 dB Typical
- Switching Speed: <35 ns
- Control Voltages: $0 \mathrm{~V} /-40 \mathrm{~V}$
- Dimensions: $4.0 \times 4.0 \times 1.42 \mathrm{~mm}$

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

## Applications

- Commercial and Military Radar
- Communications
- Electronic Warfare
- Test Instrumentation
- General Purpose


## Ordering Information

| Part No. | Description |
| :--- | :--- |
| TGS2353-2-SM | $0.5-18 \mathrm{GHz}$ High Power SPDT <br> Reflective Switch |
| 1112206 | TGS2353-2-SM Evaluation Board |

QOMVO

## Absolute Maximum Ratings

| Parameter | Rating |
| :--- | :---: |
| Control Voltage $(\mathrm{Vc})$ | -50 V |
| Control Current (lc) | $-1.5 / 6 \mathrm{~mA}$ |
| Power Dissipation | 3.5 W |
| RF Input Power, $\mathrm{CW}, 50 \Omega, \mathrm{~T}=25^{\circ} \mathrm{C}$ | 41 dBm |
| Mounting Temperature $(30 \mathrm{sec})$ | $260^{\circ} \mathrm{C}$ |
| Storage Temperature | -40 to $150^{\circ} \mathrm{C}$ |

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Recommended Operating Conditions

| Parameter |  | Min |  | Typ |
| :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{C} 1}$ |  | $-40 / 0$ |  | Max |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

## Electrical Specifications

| Parameter | Conditions ${ }^{(1)}$ | Min | Typ | Max | Units |
| :--- | :--- | :---: | :---: | :---: | :---: |
| Operational Frequency Range |  | 0.5 |  | 18 | GHz |
| Input power | CW |  | 40 |  | dBm |
| Insertion Loss | On-State |  | $<1.5$ |  | dB |
| Input Return Loss - Common Port | On-State |  | 15 |  | dB |
| Output Return Loss - Switch Port | On-State |  | 15 |  | dB |
| Isolation | Off-State |  | 30 | dB |  |
| Output Return Loss - Isolated Port | Off-State |  | 2 | dB |  |
| Insertion Loss Temperature Coefficient |  | -0.004 | $\mathrm{~dB} /{ }^{\circ} \mathrm{C}$ |  |  |
| Switching Speed - On |  |  | 31 | ns |  |
| Switching Speed - Off |  |  | 18 |  | ns |

Notes:

1. Test conditions unless otherwise noted: Temp $=+25^{\circ} \mathrm{C} . \mathrm{V}_{\mathrm{C} 1}=-40 / 0 \mathrm{~V}, \mathrm{~V}_{\mathrm{C} 2}=0 /-40 \mathrm{~V}$, see Function Table on page 6

## Thermal and Reliability Information

| Parameter | Test Conditions | Value | Units |
| :---: | :---: | :---: | :---: |
| Thermal Resistance ( $\theta_{\mathrm{Jc}}$ ) ${ }^{(1,2)}$ | $\begin{aligned} & \mathrm{T}_{\text {BASE }}=85^{\circ} \mathrm{C}, \mathrm{~V}_{\mathrm{C} 1}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{C} 2}=-40 \mathrm{~V} \text {, Freq. }=14 \mathrm{GHz} \text {, CW } \\ & \text { PIN }=40 \mathrm{dBm} \text {, Pout }=38 \mathrm{dBm} \text {, PDISS }=3.69 \mathrm{~W} \end{aligned}$ | 19.78 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Channel Temperature ( $\mathrm{T}_{\text {cH }}{ }^{(1,2)}$ |  | 158 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance ( $\theta_{\text {Jc }}$ ) ${ }^{(1,2)}$ | Tbase $=85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{c} 1}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{c} 2}=-40 \mathrm{~V}$, Freq. $=16 \mathrm{GHz}$, CW $\mathrm{P}_{\mathrm{IN}}=39.5 \mathrm{dBm}$, Роut $=36.7 \mathrm{dBm}, \mathrm{P}_{\text {DISs }}=4.24 \mathrm{~W}$ | 21.23 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Channel Temperature ( $\mathrm{T}_{\mathrm{CH}}{ }^{(1,2)}$ |  | 175 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance ( OJc $^{(1,2)}$ | $\mathrm{T}_{\text {BASE }}=85^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{C} 1}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{C} 2}=-40 \mathrm{~V}$, Freq. $=18 \mathrm{GHz}, \mathrm{CW}$ $P_{\mathrm{IN}}=39.5 \mathrm{dBm}$, Pout $=36.2 \mathrm{dBm}, \mathrm{P}_{\text {DISS }}=4.74 \mathrm{~W}$ | 21.52 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Channel Temperature ( $\mathrm{T}_{\mathrm{CH}}$ ) ${ }^{(1,2)}$ |  | 187 | ${ }^{\circ} \mathrm{C}$ |

## Notes:

1. Measured to the back of the package.
2. Refer to the following document: GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates

## Performance Plots-Small Signal






## 0.5 to 18 GHz High Power SPDT Reflective

## Performance Plots-Small Signal and Compression



## 0.5 to 18 GHz High Power SPDT Reflective

## Performance Plots-Compression and Linearity





## Evaluation Board (EVB) and Application Circuit



Notes:

1. This switch can be configured as a Single Pole, Single Throw (SPST) by terminating one unused RF switched port with a 50 Ohm load.

## Bias Up Procedure

1. $\mathrm{V}_{\mathrm{C} 1}$ or $\mathrm{V}_{\mathrm{C} 2}$ set to 0 V (see Function Table for RF Path)
2. $\mathrm{V}_{\mathrm{C} 2}$ or $\mathrm{V}_{\mathrm{C} 1}$ set to -40 V (see Function Table for RF Path)
3. Apply RF signal to RF Input

## Bias Up Down

1. Turn off RF supply
2. Turn $\mathrm{V}_{\mathrm{C} 2}$ or $\mathrm{V}_{\mathrm{C} 1}$ to 0 V
3. Turn $\mathrm{V}_{\mathrm{C} 1}$ or $\mathrm{V}_{\mathrm{C} 2}$ to 0 V

## Function Table

| RF Path | State | $\mathbf{V}_{\mathbf{C 1}}$ | $\mathbf{V}_{\mathbf{C 2}}$ |
| :--- | :--- | :---: | :---: |
|  | On-State (Insertion Loss) | 0 V | -40 V |
|  | Off-State (Isolation) | -40 V | 0 V |
| RF In to RF Out2 (50 $\Omega$ load to RF Out1) | On-State (Insertion Loss) | -40 V | 0 V |
|  | Off-State (Isolation) | 0 V | -40 V |



| Pin No. | Label | Description |
| :--- | :--- | :--- |
| $1,2,4-6,8,9$, <br> $11-17,19,20,22$ | GND | Connected to ground paddle (23); must be grounded to PCB to improve isolation. |
| 3 | RF IN | RF Input, matched to $50 \Omega ;$ DC coupled |
| 7 | VC2 | Control voltage \#2; External components are not required |
| 10 | RF OUT2 | RF switched port 2; matched to $50 \Omega ;$ DC coupled |
| 18 | RF OUT1 | RF switched port 1; matched to $50 \Omega ;$ DC coupled |
| 21 | VC1 | Control voltage \#1; External components are not required |
| 23 | GND | Backside paddle. Multiple vias should be employed to minimize inductance and thermal resistance. |

## Package Marking and Dimensions



Package lead finish:
$\mathrm{Ni} / \mathrm{Au}$ plating with minimum gold thickness of $0.5 \mu \mathrm{~m}$ Materials:
Base: Ceramic, Lid: Plastic, Part is epoxy sealed Part Marking: 23532 = Part Number, YY = Part Assembly Year, WW = Part Assembly Week, MXXX = Batch ID

Unless otherwise specified dimensions are in mm.
Tolerances: $\mathrm{XXX}= \pm 0.127$

## Assembly Notes

Compatible with lead-free soldering processes with $260^{\circ} \mathrm{C}$ peak reflow temperature.
This package is air-cavity and non-hermetic, and therefore cannot be subjected to aqueous washing. The use of no-clean solder to avoid washing after soldering is highly recommended.

Contact plating: Ni-Au
Solder rework not recommended

## Recommended Soldering Profile



TGS2353-2-SM

## 0.5 to 18 GHz High Power SPDT Reflective

## Handling Precautions

| Parameter | Rating | Standard |  |
| :--- | :--- | :--- | :--- |
| ESD - Human Body Model (HBM) | Class 1A | ESDA / JEDEC JESD22-A114 |  |
| ESD-Charge Device Model (CDM) | Class 3 | EIA/JESD22-C101 |  |
| MSL - Moisture Sensitivity Level | Level 3 | IPC/JEDEC J-STD-020 |  |

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A $\left(\mathrm{C}_{15} \mathrm{H}_{12} \mathrm{Br}_{4} \mathrm{O}_{2}\right)$ Free
- PFOS Free
- SVHC Free


## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:
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